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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/821,508	04/09/2004	Osamu Nozawa	0524-0139.02	9824
75	590 07/28/2004		EXAM	INER
Edward D. Manzo			VERSTEEG, STEVEN H	
Cook, Alex, McFarron, Manzo, Cummings & Mehler, Ltd.			ART UNIT	PAPER NUMBER
200 West Adams St., Ste. 2850 Chicago, IL 60606			1753	
			DATE MAILED: 07/28/2004	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)			
Office Action Summary		10/821,508	NOZAWA ET AL.			
		Examiner	Art Unit			
		Steven H VerSteeg	1753			
Period fo	The MAILING DATE of this communication apports.					
I HE - Exte after - If the - If NC - Failu Any	MAILING DATE OF THIS COMMUNICATION. nsions of time may be available under the provisions of 37 CFR 1.1. SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a reply operiod for reply is specified above, the maximum statutory period or reply within the set or extended period for reply will, by statute reply received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be tir y within the statutory minimum of thirty (30) day vill apply and will expire SIX (6) MONTHS from	nely filed /s will be considered timely. the mailing date of this communication.			
Status						
1)	Responsive to communication(s) filed on 09 A	oril 2004.				
		action is non-final.				
3)	3) Since this application is in condition for allowance except for formal matters, prosecution as to the ments is					
	closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Dispositi	ion of Claims	,				
4) 🔀	Claim(s) 6-10 and 12-16 is/are pending in the	annlication				
	4a) Of the above claim(s) is/are withdrawn from consideration.					
	5) Claim(s) is/are allowed.					
	Claim(s) <u>6-10 and 12-16</u> is/are rejected.					
7) Claim(s) is/are objected to.						
	Claim(s) are subject to restriction and/or	election requirement				
	on Papers	oronon roquiroment.				
	The specification is objected to by the Examine					
	The drawing(s) filed on <u>09 April 2004</u> is/are: a)[
	Applicant may not request that any objection to the o					
🗔 .	Replacement drawing sheet(s) including the correcti	on is required if the drawing(s) is obj	ected to. See 37 CFR 1.121(d).			
11)[The oath or declaration is objected to by the Ex	aminer. Note the attached Office	Action or form PTO-152.			
Priority u	nder 35 U.S.C. § 119					
a)[Acknowledgment is made of a claim for foreign ☑ All b) ☐ Some * c) ☐ None of:		-(d) or (f).			
	1. Certified copies of the priority documents have been received.					
	2. \boxtimes Certified copies of the priority documents have been received in Application No. 09/952,445.					
3. Copies of the certified copies of the priority documents have been received in this National Stage						
	application from the International Bureau					
* S	ee the attached detailed Office action for a list of	of the certified copies not receive	d.			
Attachment						
	of References Cited (PTO-892)	4) Interview Summary ((PTO-413)			
3) 🛛 Inform	of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) No(s)/Mail Date 4/9/04.		te atent Application (PTO-152)			
Paper S. Patent and Tra		6)				
TOL-326 (Re		ion Summary Par	t of Paper No /Mail Date 20040722			

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DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 6-10, 12, 14, and 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over US 5,955,2223 to Mitsui et al. (Mitsui) in view of US 2002/0106830 A1 to Ohmi et al. (Ohmi) and US 5,897,977 to Carcia et al. (Carcia).
- 3. For claim 6, Applicant requires a manufacturing method of a photo mask blank having at least a thin film for forming a pattern comprising setting a substrate in a horizontal position where a surface of the substrate on which the thin film is being formed and a surface of a sputtering target are in opposed positions with a center axis of the target deviating from a center axis of the substrate surface and sputtering the target while rotating the substrate around its center axis so as to form the thin film.
- 4. Mitsui discloses a method of making a photo mask blank (Example 1), but does not describe the specifics of the sputtering apparatus. Therefore, any generic sputtering apparatus will suffice.
- 5. Ohmi discloses a sputtering apparatus (Figure 7) that is for producing a photo mask [0005]. The target and substrate are off-center from each other (Figure 7).

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6. It would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the invention of Matsui to use the sputtering apparatus of Ohmi to make the photo mask blank because Ohmi discloses that the apparatus is useful in making photomasks.

- 7. Ohmi does not indicate that the substrate rotates.
- 8. Carcia discloses that in order to control the deposition rate and the thickness of the deposited layers, the substrates should be rotated while sputtering (col. 3, 1, 60 col. 4, 1, 11).
- 9. It would have been obvious over the prior art of record at the time the invention was made to modify the apparatus of Ohmi to rotate the substrate because of the desire to control the deposition rate and deposition thickness.
- 10. For claim 7, Applicant requires the target and substrate to form a predetermined angle between them. As can be seen from Figure 7 of Ohmi, there is a predetermined angle between the substrate and the target.
- 11. For claim 8, Applicant requires rotating the substrate integer times during formation. As noted above, Carcia shows that it is obvious to rotate the substrate.
- 12. For claims 9 and 10, Applicant requires the thin film to be a phase shift film and the blank to be a phase shift mask blank. Mitsui is making a phase shift mask blank (title).
- 13. For claim 12, Applicant requires film to be a phase shift film. Mitsui discloses making a phase shift film (Example 1).
- 14. For claim 14, Applicant requires the film to be a semi-transmission phase shift film for a halftone phase shift mask blank. Mitsui discloses the limitation (Example 1).
- 15. For claim 16, Applicant requires sputtering a target of silicon and metal in a nitrogen atmosphere so that the content of nitrogen is larger than the content of silicon. Mitsui uses a

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target of silicon and tungsten (Example 1) in a nitrogen atmosphere (Example 1) and results in a concentration of nitrogen greater than silicon (Example 1d).

Claim Objections

16. Claims 6-10 and 12-16 are objected to because of the following informalities: "in an opposed positions" should be "in opposed positions" in claim 6 at line 4. Claims 7-10 and 12-16 depend from claim 6 and contain all of the limitations of claim 6. Therefore, claims 7-10 and 12-16 are objected to for the same reasons as claim 6. Appropriate correction is required.

Double Patenting

The nonstatutory double patenting rejection is based on a judicially created doctrine grounded in public policy (a policy reflected in the statute) so as to prevent the unjustified or improper timewise extension of the "right to exclude" granted by a patent and to prevent possible harassment by multiple assignees. See *In re Goodman*, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); *In re Longi*, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985); *In re Van Ornum*, 686 F.2d 937, 214 USPQ 761 (CCPA 1982); *In re Vogel*, 422 F.2d 438, 164 USPQ 619 (CCPA 1970); and, *In re Thorington*, 418 F.2d 528, 163 USPQ 644 (CCPA 1969).

A timely filed terminal disclaimer in compliance with 37 CFR 1.321(c) may be used to overcome an actual or provisional rejection based on a nonstatutory double patenting ground provided the conflicting application or patent is shown to be commonly owned with this application. See 37 CFR 1.130(b).

Effective January 1, 1994, a registered attorney or agent of record may sign a terminal disclaimer. A terminal disclaimer signed by the assignee must fully comply with 37 CFR 3.73(b).

- 18. Claims 6-10 and 12-15 are provisionally rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claims 1 and 2 of copending Application No. 09/952,445 in view of US 2002/0106830 A1 to Ohmi et al. (Ohmi) and US 5,897,977 to Carcia et al. (Carcia).
- 19. Claims 6-10, 12, and 14 are described above. For claim 13, Applicant requires a dispersion of phase angle of the phase shift film in a plane to be within ±2°. For claim 15,

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Applicant requires a dispersion of a phase angle of the light semi-transparent phase shift film in a plane to be within $\pm 2^{\circ}$ and a dispersion of a transmittance in the plane to be within $\pm 4\%$.

- 20. The application claims a method of manufacturing a plurality of phase shift mask blanks (claim 1) or halftone phase shift mask blanks (claim 2) using a sputtering method to continuously form the phase shift film (claim 1) or the light semi-transmission film (claim 2) on the transparent substrate wherein a dispersion of phase angle of the phase shift film among the plurality of blanks is within ±2° (claim 1) and wherein dispersions of a phase angle and a transmittance of the light semi-transmission film among the plurality of halftone phase shift mask blanks are within ±2° and within ±4% respectively (claim 2).
- 21. The application does not disclose the sputtering apparatus used to form the mask blanks.
- Ohmi discloses a sputtering apparatus (Figure 7) that is for producing a photo mask [0005]. The target and substrate are off-center from each other (Figure 7).
- 23. It would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the invention of the application to use the sputtering apparatus of Ohmi to make the photo mask blank because Ohmi discloses that the apparatus is useful in making photomasks.
- 24. Ohmi does not indicate that the substrate rotates.
- 25. Carcia discloses that in order to control the deposition rate and the thickness of the deposited layers, the substrates should be rotated while sputtering (col. 3, 1, 60 col. 4, 1, 11).
- 26. It would have been obvious over the prior art of record at the time the invention was made to modify the apparatus of Ohmi to rotate the substrate because of the desire to control the deposition rate and deposition thickness.

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27. As can be seen from Figure 7 of Ohmi, there is a predetermined angle between the substrate and the target.

28. This is a <u>provisional</u> obviousness-type double patenting rejection.

General Information

For general status inquiries on applications not having received a first action on the merits, please contact the Technology Center 1700 receptionist at (571) 272-1700.

For inquiries involving Recovery of lost papers & cases, sending out missing papers, resetting shortened statutory periods, or for restarting the shortened statutory period for response, please contact Denis Boyd at (571) 272-0992.

For general inquiries such as fees, hours of operation, and employee location, please contact the Technology Center 1700 receptionist at (571) 272-1300.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Steven H VerSteeg whose telephone number is (571) 272-1348. The examiner can normally be reached on Mon - Thurs (6:30 AM - 5:00 PM).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nam X Nguyen can be reached on (571) 272-1342. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Steven H VerSteeg Primary Examiner Art Unit 1753

shv July 22, 2004